

EQUD25E2J8-27.000M

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REGULATORY COMPLIANCE (Data Sheet downloaded on Jun 2, 2020)


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ITEM DESCRIPTION

Temperature Compensated Voltage Controlled Quartz Crystal Clock Oscillators TCVCXO Clipped Sinewave 3.0Vdc 4 Pad 3.2mm x 5.0mm Ceramic Surface Mount (SMD) 27.000MHz -10°C to +60°C

ELECTRICAL SPECIFICATIONS

Nominal Frequency	27.000MHz
Frequency Stability	±1.0ppm Maximum (Inclusive of Operating Temperature Range, At Vdd=3.0Vdc and Vc=1.5Vdc)
Frequency Stability vs. Frequency Tolerance	±1.0ppm Maximum (at 25°C ±2°C, at Vdd=3.0Vdc, and Vc=1.5Vdc, Pre-Reflow)
Frequency Stability vs. Input Voltage	±0.2ppm Maximum (±5%)
Frequency Stability vs. Load	±0.2ppm Maximum (±1kOhm//±1pF)
Frequency Stability vs. Reflow	±1.0ppm Maximum (at 25°C, 1 Hour after Reflow, 2 Times)
Frequency Stability vs. Aging	±1.0ppm/year Maximum (at 25°C)
Operating Temperature Range	-10°C to +60°C
Supply Voltage	3.0Vdc ±5%
Input Current	2.5mA Maximum
Output Voltage	0.7Vp-p Clipped Sinewave Minimum (External DC-Cut capacitor required, 1000pF recommended)
Load Drive Capability	10kOhms//10pF
Output Logic Type	Clipped Sinewave
Control Voltage	1.5Vdc ±1.0Vdc
Frequency Deviation	±8ppm Minimum
Linearity	10% Maximum
Transfer Function	Positive Transfer Characteristic
Modulation Bandwidth	10kHz Minimum at -3dB
Input Impedance	1Mohm Minimum
Phase Noise	All Values are Typical -80dBc/Hz at 10Hz Offset -115dBc/Hz at 100Hz Offset -135dBc/Hz at 1kHz Offset -148dBc/Hz at 10kHz Offset
RMS Phase Jitter	1pSec Maximum (Fj=12kHz to 20MHz (Random))
Start Up Time	5mSec Maximum
Storage Temperature Range	-40°C to +85°C

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS

ESD Susceptibility	MIL-STD-883, Method 3015, Class 1, HBM: 1500V
Fine Leak Test	MIL-STD-883, Method 1014, Condition A
Flammability	UL94-V0
Gross Leak Test	MIL-STD-883, Method 1014, Condition C
Mechanical Shock	MIL-STD-883, Method 2002, Condition B
Moisture Resistance	MIL-STD-883, Method 1004
Moisture Sensitivity	J-STD-020, MSL 1
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition K
Resistance to Solvents	MIL-STD-202, Method 215
Solderability	MIL-STD-883, Method 2003

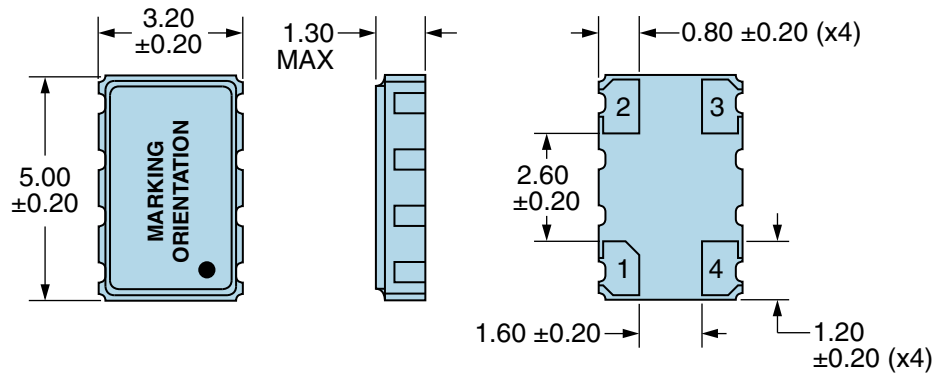
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ENVIRONMENTAL & MECHANICAL SPECIFICATIONS CONTINUED

Temperature Cycling	MIL-STD-883, Method 1010, Condition B
Vibration	MIL-STD-883, Method 2007, Condition A

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MECHANICAL DIMENSIONS (all dimensions in millimeters)

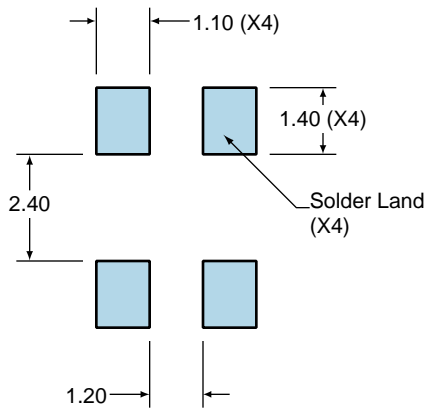


PIN	CONNECTION
1	Control Voltage
2	Case/Ground
3	Output
4	Supply Voltage

LINE	MARKING
1	E27.000 E=Ecliptek Designator
2	XXXXX XXXXX=Ecliptek Manufacturing Identifier

Suggested Solder Pad Layout

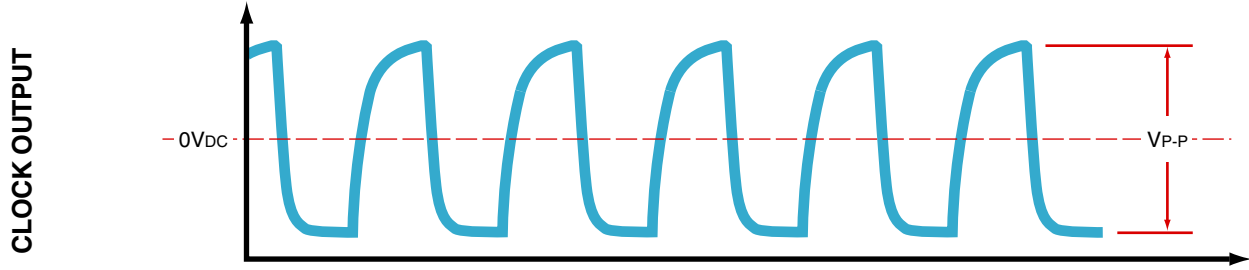
All Dimensions in Millimeters



All Tolerances are ± 0.1

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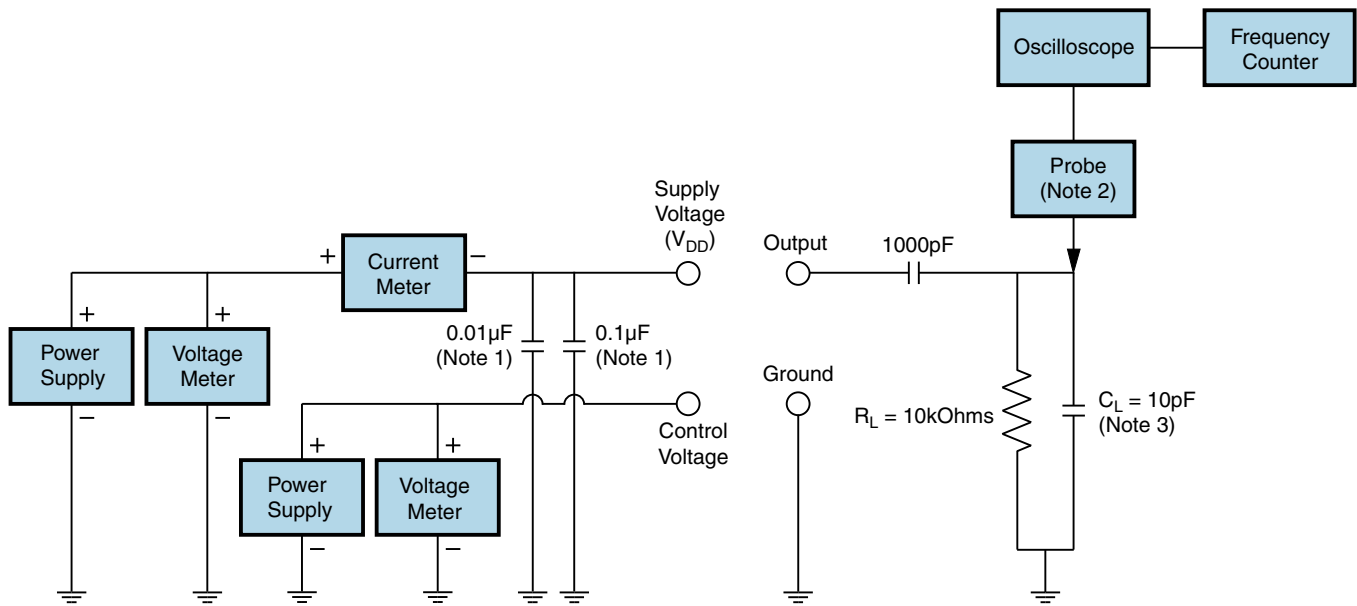
OUTPUT WAVEFORM



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Test Circuit for Clipped Sinewave Output



Note 1: An external 0.01µF bypass capacitor in parallel with a 0.1µF high frequency ceramic bypass capacitor close (less than 2mm) to the package ground and supply voltage pin is required.

Note 2: A low input capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value C_L includes sum of all probe and fixture capacitance.